

# NCP45540

## ecoSWITCH™ Advanced Load Management

### Controlled Load Switch with Low $R_{ON}$

The NCP45540 load switch provides a component and area-reducing solution for efficient power domain switching with inrush current limit via soft-start. In addition to integrated control functionality with ultra low on-resistance, this device offers system safeguards and monitoring via fault protection and power good signaling. This cost effective solution is ideal for power management and hot-swap applications requiring low power consumption in a small footprint.

#### Features

- Advanced Controller with Charge Pump
- Integrated N-Channel MOSFET with Low  $R_{ON}$
- Input Voltage Range 0.5 V to 13.5 V
- Soft-Start via Controlled Slew Rate
- Adjustable Slew Rate Control
- Power Good Signal
- Thermal Shutdown
- Undervoltage Lockout
- Short-Circuit Protection
- Extremely Low Standby Current
- Load Bleed (Quick Discharge)
- This is a Pb-Free Device

#### Typical Applications

- Portable Electronics and Systems
- Notebook and Tablet Computers
- Telecom, Networking, Medical, and Industrial Equipment
- Set-Top Boxes, Servers, and Gateways
- Hot-Swap Devices and Peripheral Ports

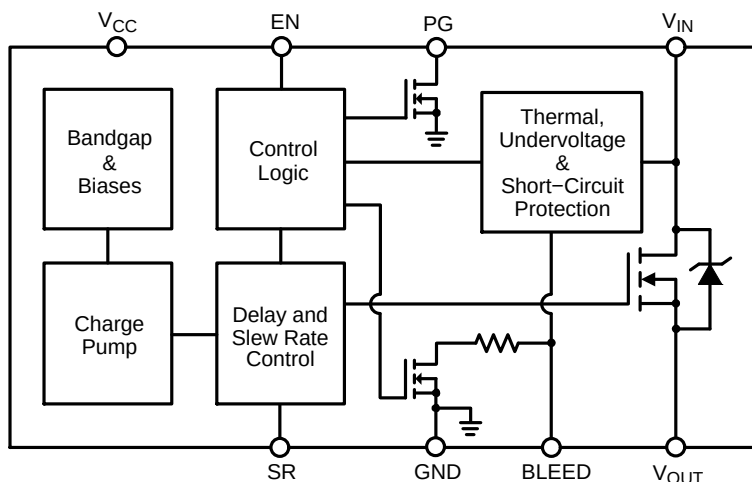


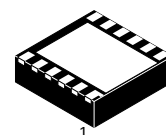
Figure 1. Block Diagram



ON Semiconductor®

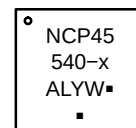
[www.onsemi.com](http://www.onsemi.com)

| $R_{ON}$ TYP | $V_{CC}$ | $V_{IN}$ | $I_{MAX}$ |
|--------------|----------|----------|-----------|
| 3.3 mΩ       | 3.3 V    | 1.8 V    | 20 A      |
| 3.6 mΩ       | 3.3 V    | 5.0 V    |           |
| 4.8 mΩ       | 3.3 V    | 12 V     |           |



DFN12, 3x3  
CASE 506CD

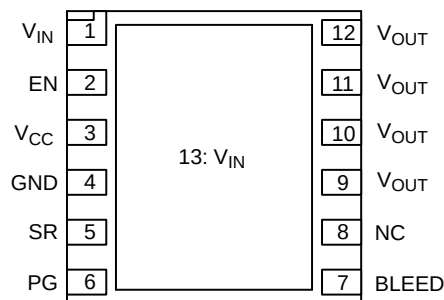
#### MARKING DIAGRAM



x = H for NCP45540-H  
= L for NCP45540-L  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

#### PIN CONFIGURATION



(Top View)

#### ORDERING INFORMATION

See detailed ordering and shipping information on page 12 of this data sheet.

# NCP45540

**Table 1. PIN DESCRIPTION**

| Pin   | Name             | Function                                                                                                                                                                                    |
|-------|------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1, 13 | V <sub>IN</sub>  | Drain of MOSFET (0.5 V – 13.5 V), Pin 1 must be connected to Pin 13                                                                                                                         |
| 2     | EN               | NCP45540–H – Active–high digital input used to turn on the MOSFET, pin has an internal pull down resistor to GND                                                                            |
|       |                  | NCP45540–L – Active–low digital input used to turn on the MOSFET, pin has an internal pull up resistor to V <sub>CC</sub>                                                                   |
| 3     | V <sub>CC</sub>  | Supply voltage to controller (3.0 V – 5.5 V)                                                                                                                                                |
| 4     | GND              | Controller ground                                                                                                                                                                           |
| 5     | SR               | Slew rate adjustment; float if not used                                                                                                                                                     |
| 6     | PG               | Active–high, open–drain output that indicates when the gate of the MOSFET is fully driven, external pull up resistor ≥ 1 kΩ to an external voltage source required; tie to GND if not used. |
| 7     | BLEED            | Load bleed connection, must be tied to V <sub>OUT</sub> either directly or through a resistor ≤ 1 kΩ                                                                                        |
| 8     | NC               | No connect, internally floating but pin may be tied to V <sub>OUT</sub>                                                                                                                     |
| 9–12  | V <sub>OUT</sub> | Source of MOSFET connected to load                                                                                                                                                          |

**Table 2. ABSOLUTE MAXIMUM RATINGS**

| Rating                                                                                         | Symbol             | Value                           | Unit       |
|------------------------------------------------------------------------------------------------|--------------------|---------------------------------|------------|
| Supply Voltage Range                                                                           | V <sub>CC</sub>    | –0.3 to 6                       | V          |
| Input Voltage Range                                                                            | V <sub>IN</sub>    | –0.3 to 18                      | V          |
| Output Voltage Range                                                                           | V <sub>OUT</sub>   | –0.3 to 18                      | V          |
| EN Digital Input Range                                                                         | V <sub>EN</sub>    | –0.3 to (V <sub>CC</sub> + 0.3) | V          |
| PG Output Voltage Range (Note 1)                                                               | V <sub>PG</sub>    | –0.3 to 6                       | V          |
| Thermal Resistance, Junction–to–Ambient, Steady State (Note 2)                                 | R <sub>θJA</sub>   | 30.9                            | °C/W       |
| Thermal Resistance, Junction–to–Ambient, Steady State (Note 3)                                 | R <sub>θJA</sub>   | 51.3                            | °C/W       |
| Thermal Resistance, Junction–to–Case (V <sub>IN</sub> Paddle)                                  | R <sub>θJC</sub>   | 3.5                             | °C/W       |
| Continuous MOSFET Current @ T <sub>A</sub> = 25°C (Notes 2 and 4)                              | I <sub>MAX</sub>   | 20                              | A          |
| Continuous MOSFET Current @ T <sub>A</sub> = 25°C (Notes 3 and 4)                              | I <sub>MAX</sub>   | 15.5                            | A          |
| Total Power Dissipation @ T <sub>A</sub> = 25°C (Note 2)<br>Derate above T <sub>A</sub> = 25°C | P <sub>D</sub>     | 3.24<br>32.4                    | W<br>mW/°C |
| Total Power Dissipation @ T <sub>A</sub> = 25°C (Note 3)<br>Derate above T <sub>A</sub> = 25°C | P <sub>D</sub>     | 1.95<br>19.5                    | W<br>mW/°C |
| Storage Temperature Range                                                                      | T <sub>STG</sub>   | –40 to 150                      | °C         |
| Lead Temperature, Soldering (10 sec.)                                                          | T <sub>SLD</sub>   | 260                             | °C         |
| ESD Capability, Human Body Model (Notes 5 and 6)                                               | ESD <sub>HBM</sub> | 3.0                             | kV         |
| ESD Capability, Charged Device Model (Note 5)                                                  | ESD <sub>CDM</sub> | 1.0                             | kV         |
| Latch–up Current Immunity (Notes 5 and 6)                                                      | LU                 | 100                             | mA         |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. PG is an open–drain output that requires an external pull up resistor ≥ 1 kΩ to an external voltage source.
2. Surface–mounted on FR4 board using 1 sq–in pad, 1 oz Cu.
3. Surface–mounted on FR4 board using the minimum recommended pad size, 1 oz Cu.
4. Ensure that the expected operating MOSFET current will not cause the Short–Circuit Protection to turn the MOSFET off undesirably.
5. Tested by the following methods @ T<sub>A</sub> = 25°C:  
 ESD Human Body Model tested per JESD22–A114  
 ESD Charged Device Model per ESD STM5.3.1  
 Latch–up Current tested per JESD78
6. Rating is for all pins except for V<sub>IN</sub> and V<sub>OUT</sub> which are tied to the internal MOSFET's Drain and Source. Typical MOSFET ESD performance for V<sub>IN</sub> and V<sub>OUT</sub> should be expected and these devices should be treated as ESD sensitive.

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**Table 3. OPERATING RANGES**

| Rating               | Symbol   | Min | Max  | Unit |
|----------------------|----------|-----|------|------|
| Supply Voltage       | $V_{CC}$ | 3   | 5.5  | V    |
| Input Voltage        | $V_{IN}$ | 0.5 | 13.5 | V    |
| Ground               | GND      |     | 0    | V    |
| Ambient Temperature  | $T_A$    | -40 | 85   | °C   |
| Junction Temperature | $T_J$    | -40 | 125  | °C   |

**Table 4. ELECTRICAL CHARACTERISTICS** ( $T_J = 25^\circ\text{C}$  unless otherwise specified)

| Parameter                                | Conditions (Note 7)                                     | Symbol      | Min  | Typ  | Max  | Unit |
|------------------------------------------|---------------------------------------------------------|-------------|------|------|------|------|
| <b>MOSFET</b>                            |                                                         |             |      |      |      |      |
| On-Resistance                            | $V_{CC} = 3.3\text{ V}; V_{IN} = 1.8\text{ V}$          | $R_{ON}$    |      | 3.3  | 4.5  | mΩ   |
|                                          | $V_{CC} = 3.3\text{ V}; V_{IN} = 5\text{ V}$            |             |      | 3.6  | 4.9  |      |
|                                          | $V_{CC} = 3.3\text{ V}; V_{IN} = 12\text{ V}$           |             |      | 4.8  | 7.7  |      |
| Leakage Current (Note 8)                 | $V_{EN} = 0\text{ V}; V_{IN} = 13.5\text{ V}$           | $I_{LEAK}$  |      | 0.1  | 1.0  | μA   |
| <b>CONTROLLER</b>                        |                                                         |             |      |      |      |      |
| Supply Standby Current (Note 9)          | $V_{EN} = 0\text{ V}; V_{CC} = 3\text{ V}$              | $I_{STBY}$  |      | 0.65 | 2.0  | μA   |
|                                          | $V_{EN} = 0\text{ V}; V_{CC} = 5.5\text{ V}$            |             |      | 3.2  | 4.5  |      |
| Supply Dynamic Current (Note 10)         | $V_{EN} = V_{CC} = 3\text{ V}; V_{IN} = 12\text{ V}$    | $I_{DYN}$   |      | 280  | 400  | μA   |
|                                          | $V_{EN} = V_{CC} = 5.5\text{ V}; V_{IN} = 1.8\text{ V}$ |             |      | 530  | 750  |      |
| Bleed Resistance                         | $V_{EN} = 0\text{ V}; V_{CC} = 3\text{ V}$              | $R_{BLEED}$ | 86   | 115  | 144  | Ω    |
|                                          | $V_{EN} = 0\text{ V}; V_{CC} = 5.5\text{ V}$            |             | 72   | 97   | 121  |      |
| Bleed Pin Leakage Current                | $V_{EN} = V_{CC} = 3\text{ V}; V_{IN} = 1.8\text{ V}$   | $I_{BLEED}$ |      | 6.0  | 10   | μA   |
|                                          | $V_{EN} = V_{CC} = 3\text{ V}; V_{IN} = 12\text{ V}$    |             |      | 60   | 70   |      |
| EN Input High Voltage                    | $V_{CC} = 3\text{ V} - 5.5\text{ V}$                    | $V_{IH}$    | 2.0  |      |      | V    |
| EN Input Low Voltage                     | $V_{CC} = 3\text{ V} - 5.5\text{ V}$                    | $V_{IL}$    |      |      | 0.8  | V    |
| EN Input Leakage Current                 | NCP45540-H; $V_{EN} = 0\text{ V}$                       | $I_{IL}$    |      | 90   | 500  | nA   |
|                                          | NCP45540-L; $V_{EN} = V_{CC}$                           | $I_{IH}$    |      | 90   | 500  |      |
| EN Pull Down Resistance                  | NCP45540-H                                              | $R_{PD}$    | 76   | 100  | 124  | kΩ   |
| EN Pull Up Resistance                    | NCP45540-L                                              | $R_{PU}$    | 76   | 100  | 124  | kΩ   |
| PG Output Low Voltage (Note 11)          | $V_{CC} = 3\text{ V}; I_{SINK} = 5\text{ mA}$           | $V_{OL}$    |      |      | 0.2  | V    |
| PG Output Leakage Current (Note 12)      | $V_{CC} = 3\text{ V}; V_{TERM} = 3.3\text{ V}$          | $I_{OH}$    |      | 5.0  | 100  | nA   |
| Slew Rate Control Constant (Note 13)     | $V_{CC} = 3\text{ V}$                                   | $K_{SR}$    | 26   | 33   | 40   | μA   |
| <b>FAULT PROTECTIONS</b>                 |                                                         |             |      |      |      |      |
| Thermal Shutdown Threshold (Note 14)     | $V_{CC} = 3\text{ V} - 5.5\text{ V}$                    | $T_{SDT}$   |      | 145  |      | °C   |
| Thermal Shutdown Hysteresis (Note 14)    | $V_{CC} = 3\text{ V} - 5.5\text{ V}$                    | $T_{HYS}$   |      | 20   |      | °C   |
| $V_{IN}$ Undervoltage Lockout Threshold  | $V_{CC} = 3\text{ V}$                                   | $V_{UVLO}$  | 0.25 | 0.35 | 0.45 | V    |
| $V_{IN}$ Undervoltage Lockout Hysteresis | $V_{CC} = 3\text{ V}$                                   | $V_{HYS}$   | 25   | 40   | 60   | mV   |
| Short-Circuit Protection Threshold       | $V_{CC} = 3\text{ V}; V_{IN} = 0.5\text{ V}$            | $V_{SC}$    | 200  | 265  | 350  | mV   |
|                                          | $V_{CC} = 3\text{ V}; V_{IN} = 13.5\text{ V}$           |             | 100  | 285  | 500  |      |

7.  $V_{EN}$  shown only for NCP45540-H, (EN Active-High) unless otherwise specified.

8. Average current from  $V_{IN}$  to  $V_{OUT}$  with MOSFET turned off.

9. Average current from  $V_{CC}$  to GND with MOSFET turned off.

10. Average current from  $V_{CC}$  to GND after charge up time of MOSFET.

11. PG is an open-drain output that is pulled low when the MOSFET is disabled.

12. PG is an open-drain output that is not driven when the gate of the MOSFET is fully charged, requires an external pull up resistor  $\geq 1\text{ k}\Omega$  to an external voltage source,  $V_{TERM}$ .

13. See Applications Information section for details on how to adjust the slew rate.

14. Operation above  $T_J = 125^\circ\text{C}$  is not guaranteed.

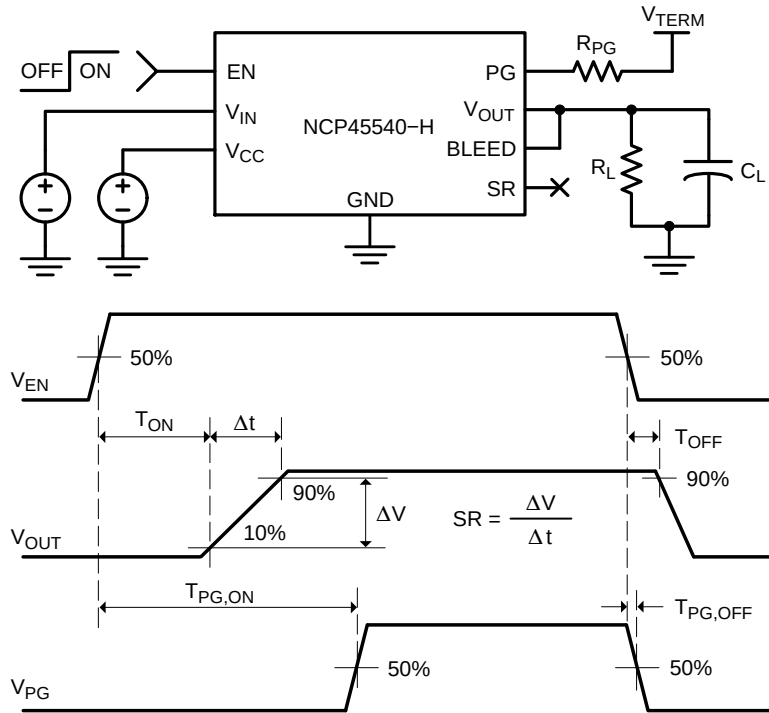
# NCP45540

**Table 5. SWITCHING CHARACTERISTICS** ( $T_J = 25^\circ\text{C}$  unless otherwise specified) (Notes 15 and 16)

| Parameter                | Conditions                                     | Symbol       | Min | Typ  | Max | Unit          |
|--------------------------|------------------------------------------------|--------------|-----|------|-----|---------------|
| Output Slew Rate         | $V_{CC} = 3.3\text{ V}; V_{IN} = 1.8\text{ V}$ | SR           |     | 11.8 |     | kV/s          |
|                          | $V_{CC} = 5.0\text{ V}; V_{IN} = 1.8\text{ V}$ |              |     | 12.0 |     |               |
|                          | $V_{CC} = 3.3\text{ V}; V_{IN} = 12\text{ V}$  |              |     | 13.3 |     |               |
|                          | $V_{CC} = 5.0\text{ V}; V_{IN} = 12\text{ V}$  |              |     | 13.5 |     |               |
| Output Turn-on Delay     | $V_{CC} = 3.3\text{ V}; V_{IN} = 1.8\text{ V}$ | $T_{ON}$     |     | 200  |     | $\mu\text{s}$ |
|                          | $V_{CC} = 5.0\text{ V}; V_{IN} = 1.8\text{ V}$ |              |     | 170  |     |               |
|                          | $V_{CC} = 3.3\text{ V}; V_{IN} = 12\text{ V}$  |              |     | 260  |     |               |
|                          | $V_{CC} = 5.0\text{ V}; V_{IN} = 12\text{ V}$  |              |     | 250  |     |               |
| Output Turn-off Delay    | $V_{CC} = 3.3\text{ V}; V_{IN} = 1.8\text{ V}$ | $T_{OFF}$    |     | 2.0  |     | $\mu\text{s}$ |
|                          | $V_{CC} = 5.0\text{ V}; V_{IN} = 1.8\text{ V}$ |              |     | 1.6  |     |               |
|                          | $V_{CC} = 3.3\text{ V}; V_{IN} = 12\text{ V}$  |              |     | 0.7  |     |               |
|                          | $V_{CC} = 5.0\text{ V}; V_{IN} = 12\text{ V}$  |              |     | 0.4  |     |               |
| Power Good Turn-on Time  | $V_{CC} = 3.3\text{ V}; V_{IN} = 1.8\text{ V}$ | $T_{PG,ON}$  |     | 1.02 |     | ms            |
|                          | $V_{CC} = 5.0\text{ V}; V_{IN} = 1.8\text{ V}$ |              |     | 0.95 |     |               |
|                          | $V_{CC} = 3.3\text{ V}; V_{IN} = 12\text{ V}$  |              |     | 1.52 |     |               |
|                          | $V_{CC} = 5.0\text{ V}; V_{IN} = 12\text{ V}$  |              |     | 1.23 |     |               |
| Power Good Turn-off Time | $V_{CC} = 3.3\text{ V}; V_{IN} = 1.8\text{ V}$ | $T_{PG,OFF}$ |     | 20   |     | ns            |
|                          | $V_{CC} = 5.0\text{ V}; V_{IN} = 1.8\text{ V}$ |              |     | 14   |     |               |
|                          | $V_{CC} = 3.3\text{ V}; V_{IN} = 12\text{ V}$  |              |     | 20   |     |               |
|                          | $V_{CC} = 5.0\text{ V}; V_{IN} = 12\text{ V}$  |              |     | 14   |     |               |

15. See below figure for Test Circuit and Timing Diagram.

16. Tested with the following conditions:  $V_{TERM} = V_{CC}$ ;  $R_{PG} = 100\text{ k}\Omega$ ;  $R_L = 10\text{ }\Omega$ ;  $C_L = 0.1\text{ }\mu\text{F}$ .



**Figure 2. Switching Characteristics Test Circuit and Timing Diagrams**

# TYPICAL CHARACTERISTICS

( $T_J = 25^\circ\text{C}$  unless otherwise specified)

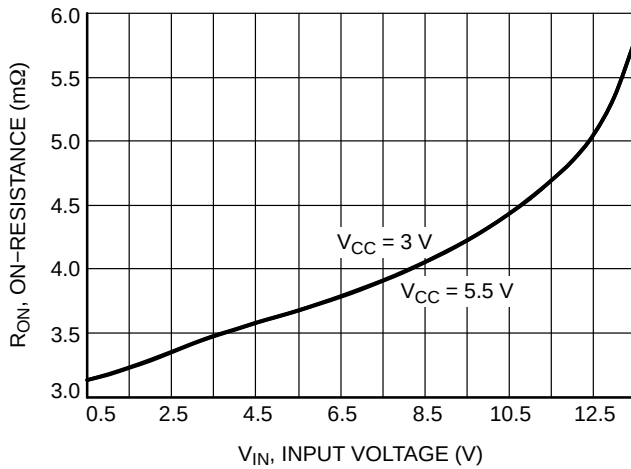


Figure 3. On-Resistance vs. Input Voltage

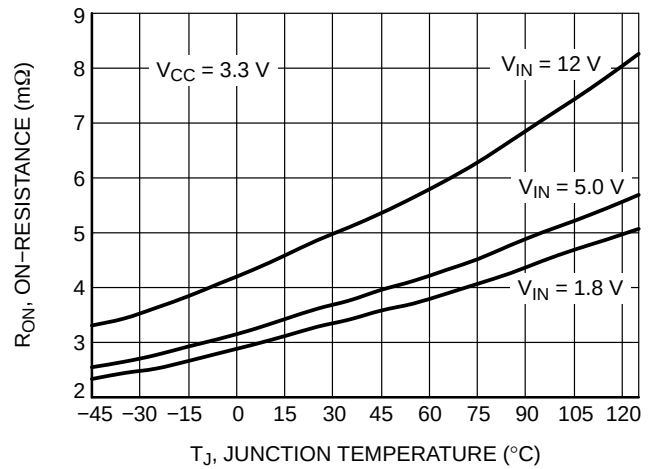


Figure 4. On-Resistance vs. Temperature

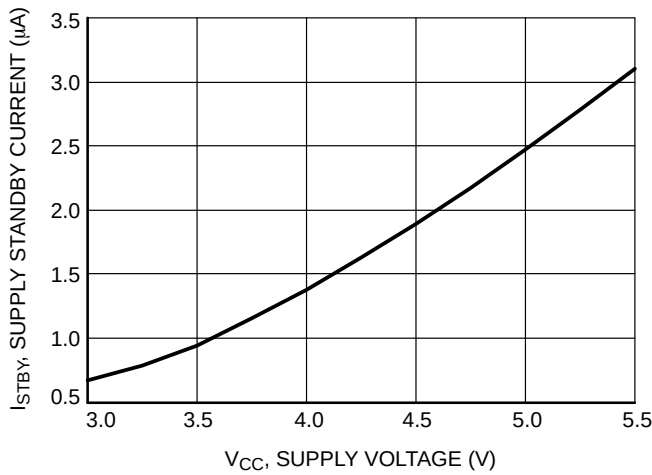


Figure 5. Supply Standby Current vs. Supply Voltage

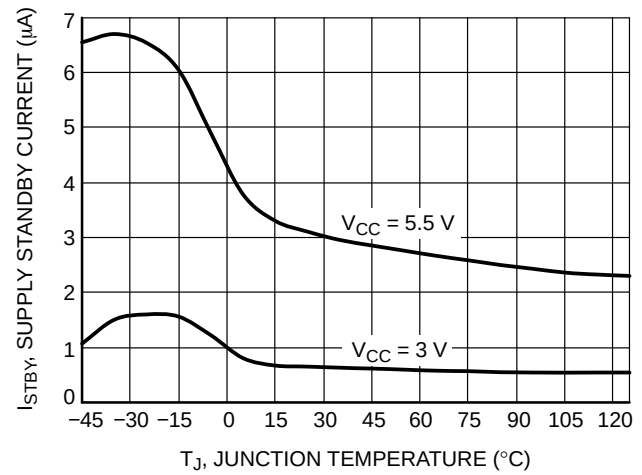


Figure 6. Supply Standby Current vs. Temperature

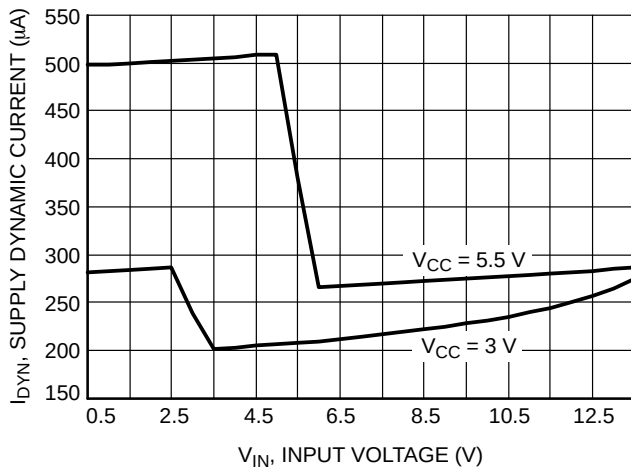


Figure 7. Supply Dynamic Current vs. Input Voltage

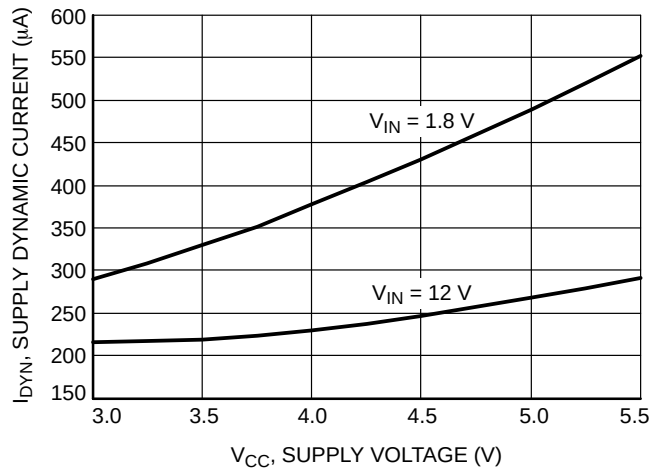


Figure 8. Supply Dynamic Current vs. Supply Voltage

TYPICAL CHARACTERISTICS

( $T_J = 25^\circ\text{C}$  unless otherwise specified)

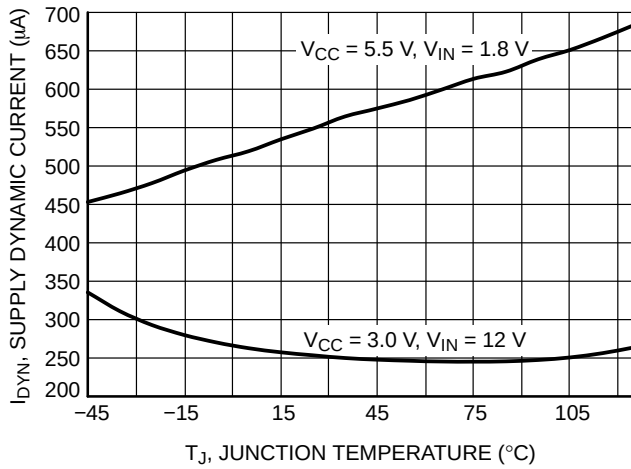


Figure 9. Supply Dynamic Current vs. Temperature

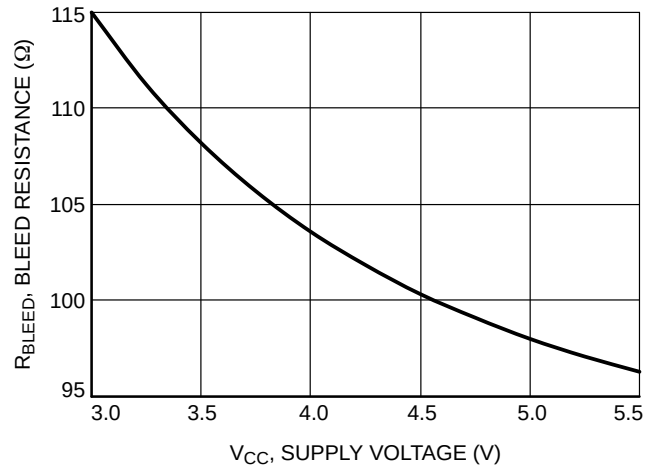


Figure 10. Bleed Resistance vs. Supply Voltage

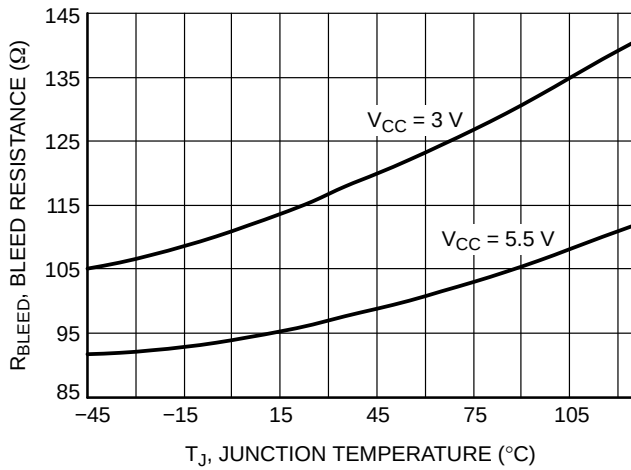


Figure 11. Bleed Resistance vs. Temperature

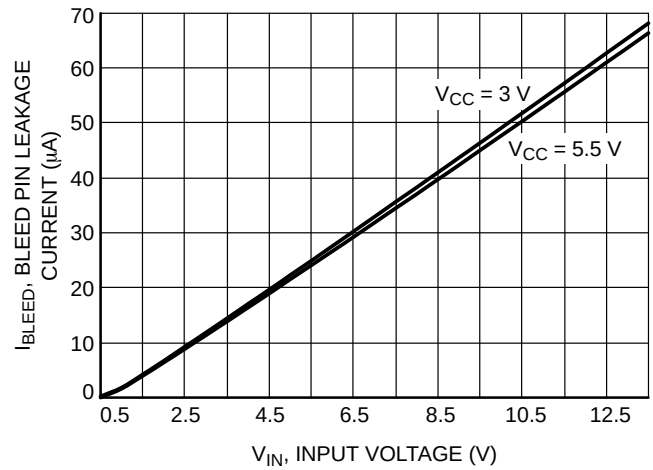


Figure 12. Bleed Pin Leakage Current vs. Input Voltage

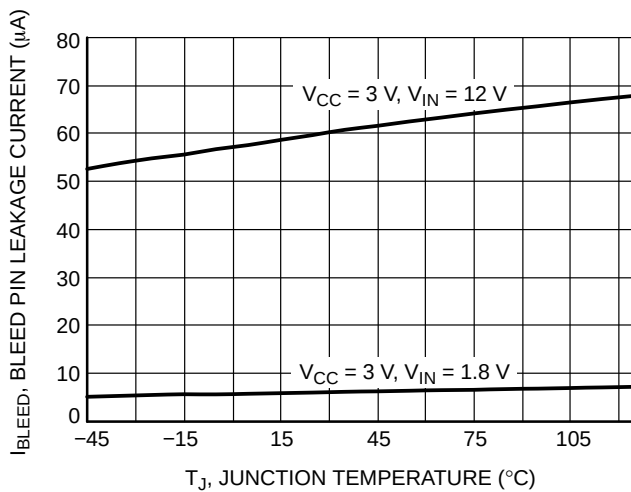


Figure 13. Bleed Pin Leakage Current vs. Temperature

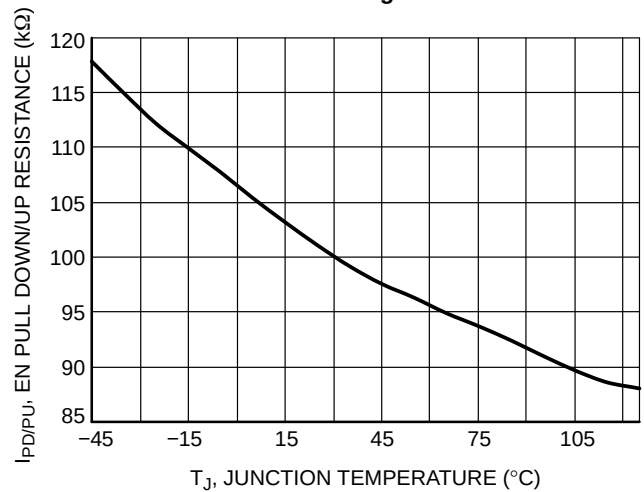


Figure 14. EN Pull Down/Up Resistance vs. Temperature

# TYPICAL CHARACTERISTICS

( $T_J = 25^\circ\text{C}$  unless otherwise specified)

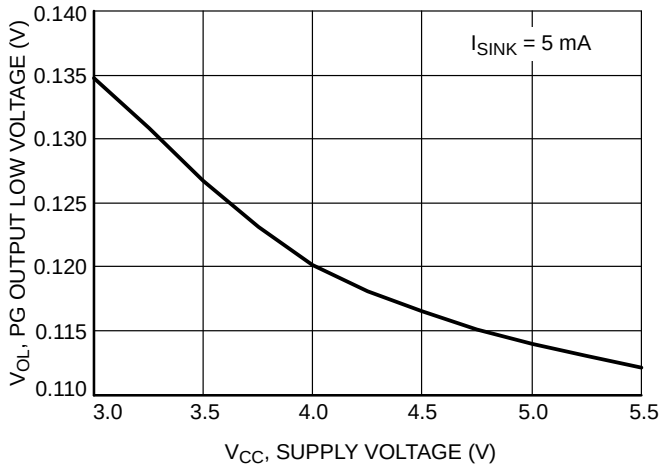


Figure 15. PG Output Low Voltage vs. Supply Voltage

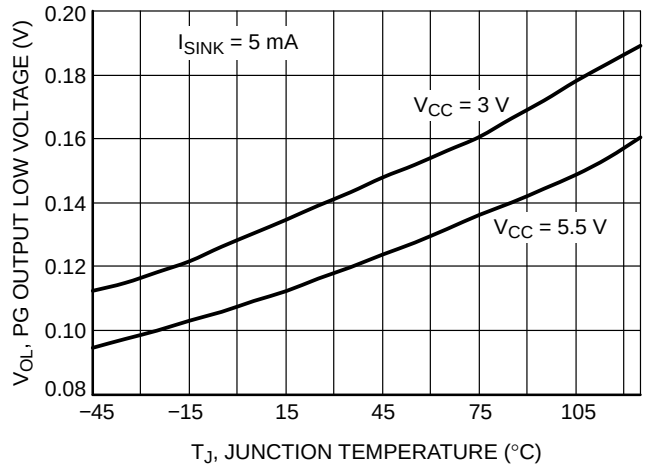


Figure 16. PG Output Low Voltage vs. Temperature

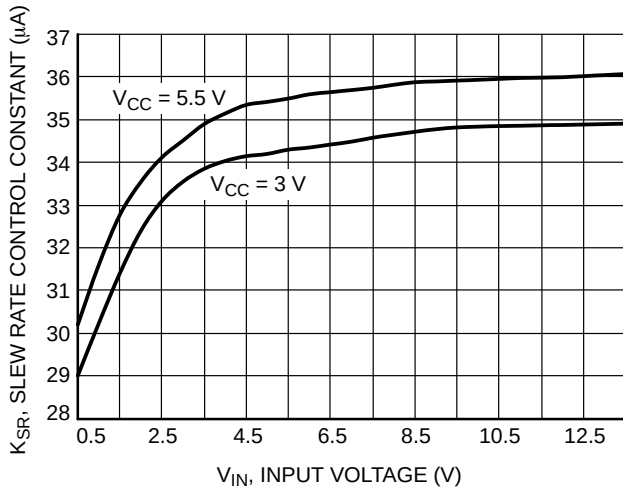


Figure 17. Slew Rate Control Constant vs. Input Voltage

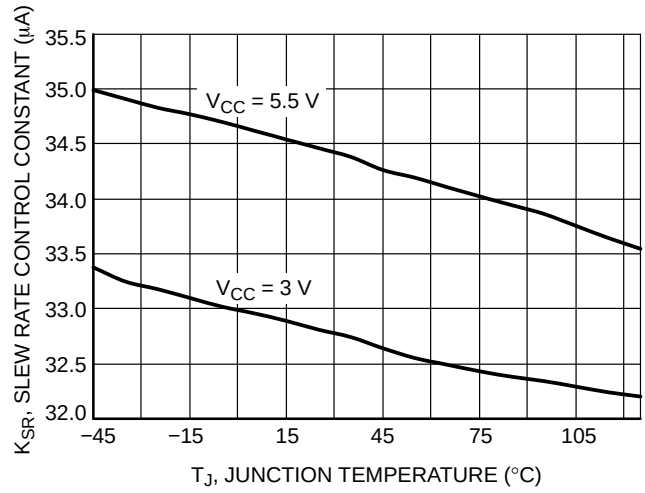


Figure 18. Slew Rate Control Constant vs. Temperature

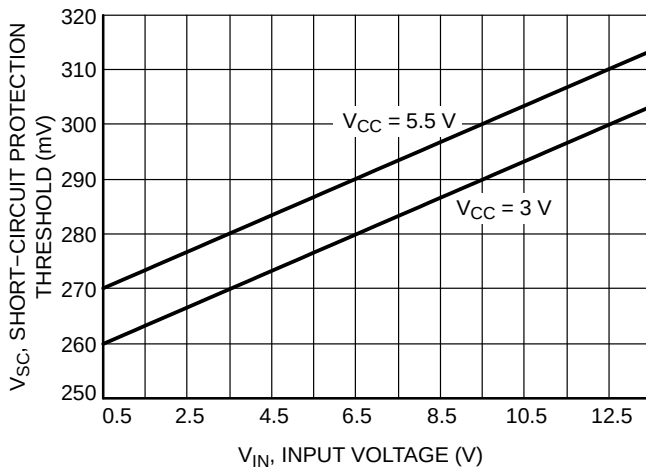


Figure 19. Short-Circuit Protection Threshold vs. Input Voltage

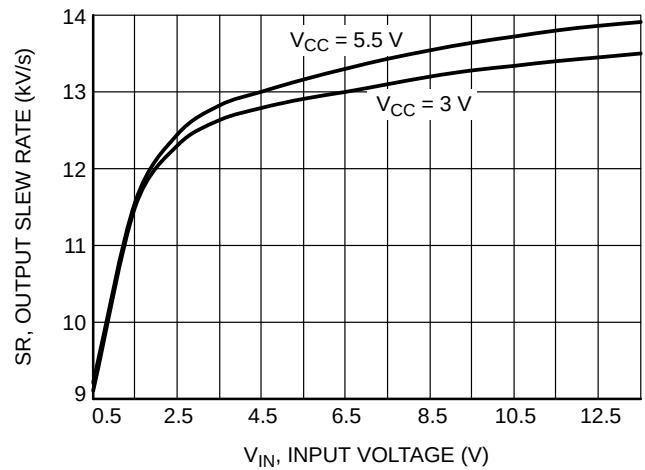


Figure 20. Output Slew Rate vs. Input Voltage

# TYPICAL CHARACTERISTICS

( $T_J = 25^\circ\text{C}$  unless otherwise specified)

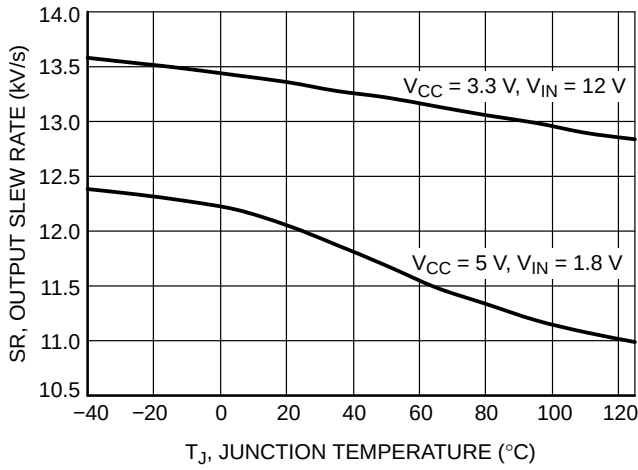


Figure 21. Output Slew Rate vs. Temperature

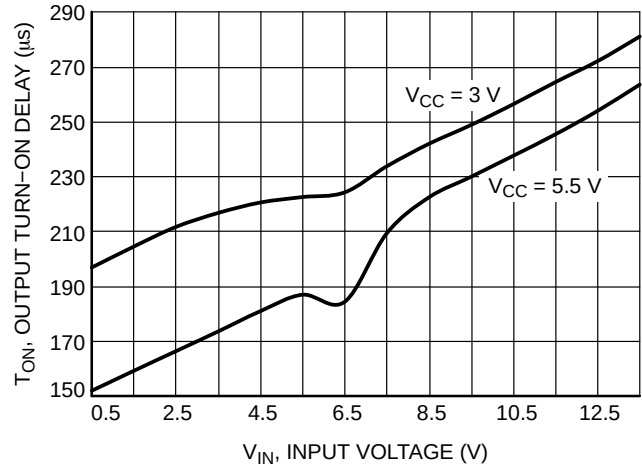


Figure 22. Output Turn-on Delay vs. Input Voltage

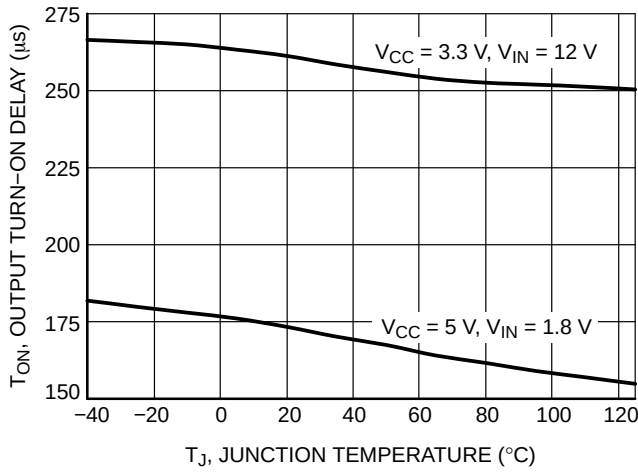


Figure 23. Output Turn-on Delay vs. Temperature

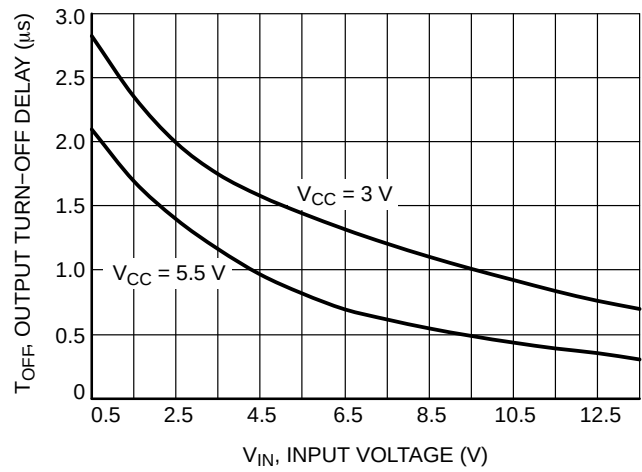


Figure 24. Output Turn-off Delay vs. Input Voltage

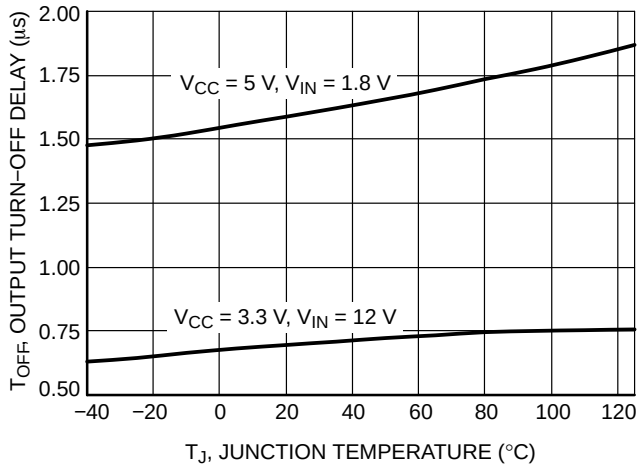


Figure 25. Output Turn-off Delay vs. Temperature

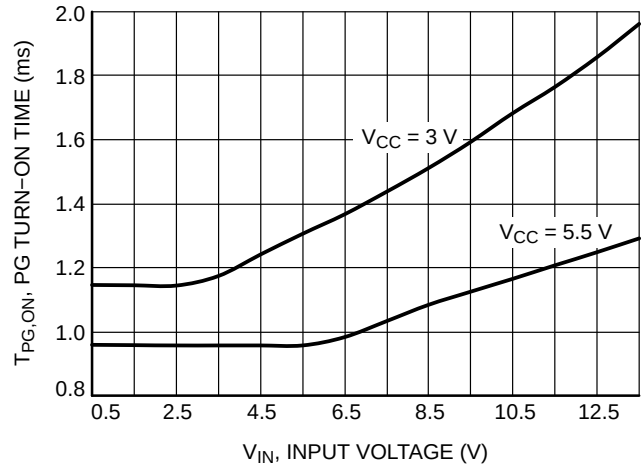


Figure 26. Power Good Turn-on Time vs. Input Voltage



TYPICAL CHARACTERISTICS

( $T_J = 25^\circ\text{C}$  unless otherwise specified)

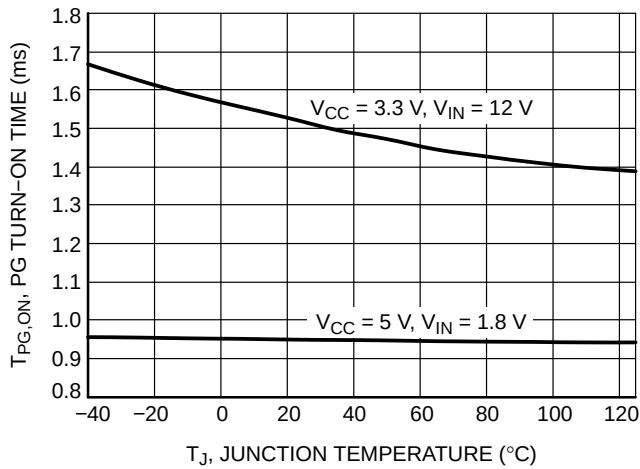


Figure 27. Power Good Turn-on Time vs. Temperature

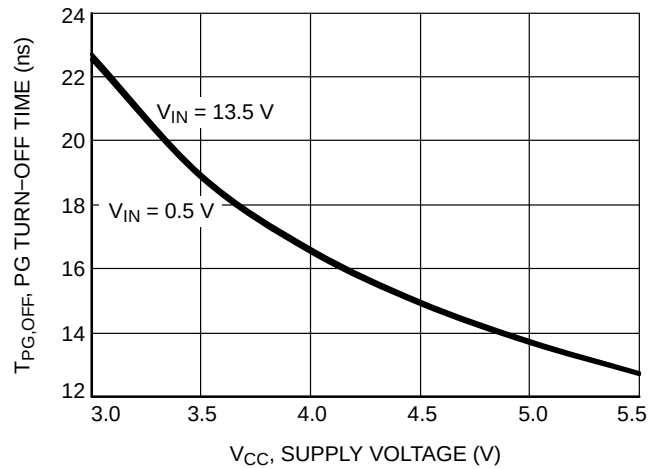


Figure 28. Power Good Turn-off Time vs. Supply Voltage

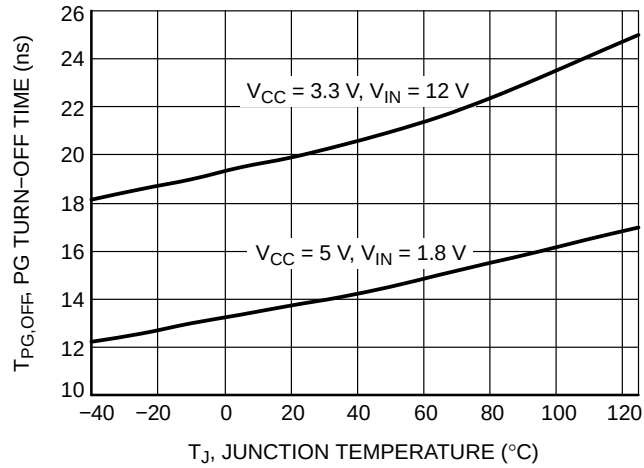


Figure 29. Power Good Turn-off Time vs. Temperature

## APPLICATIONS INFORMATION

**Enable Control**

The NCP45540 has two part numbers, NCP45540-H and NCP45540-L, that only differ in the polarity of the enable control.

The NCP45540-H device allows for enabling the MOSFET in an active-high configuration. When the  $V_{CC}$  supply pin has an adequate voltage applied and the EN pin is at a logic high level, the MOSFET will be enabled. Similarly, when the EN pin is at a logic low level, the MOSFET will be disabled. An internal pull down resistor to ground on the EN pin ensures that the MOSFET will be disabled when not being driven.

The NCP45540-L device allows for enabling the MOSFET in an active-low configuration. When the  $V_{CC}$  supply pin has an adequate voltage applied and the EN pin is at a logic low level, the MOSFET will be enabled. Similarly, when the EN pin is at a logic high level, the MOSFET will be disabled. An internal pull up resistor to  $V_{CC}$  on the EN pin ensures that the MOSFET will be disabled when not being driven.

**Power Sequencing**

The NCP45540 devices will function with any power sequence, but the output turn-on delay performance may vary from what is specified. To achieve the specified performance, there are two recommended power sequences:

1.  $V_{CC} \rightarrow V_{IN} \rightarrow V_{EN}$
2.  $V_{IN} \rightarrow V_{CC} \rightarrow V_{EN}$

**Load Bleed (Quick Discharge)**

The NCP45540 devices have an internal bleed resistor,  $R_{BLEED}$ , which is used to bleed the charge off of the load to ground after the MOSFET has been disabled. In series with the bleed resistor is a bleed switch that is enabled whenever the MOSFET is disabled. The MOSFET and the bleed switch are never concurrently active.

It is required that the BLEED pin be connected to  $V_{OUT}$  either directly (as shown in Figure 31) or through an external resistor,  $R_{EXT}$  (as shown in Figure 30).  $R_{EXT}$  should not exceed 1 k $\Omega$  and can be used to increase the total bleed resistance.

Care must be taken to ensure that the power dissipated across  $R_{BLEED}$  is kept at a safe level. The maximum continuous power that can be dissipated across  $R_{BLEED}$  is 0.4 W.  $R_{EXT}$  can be used to decrease the amount of power dissipated across  $R_{BLEED}$ .

**Power Good**

The NCP45540 devices have a power good output (PG) that can be used to indicate when the gate of the MOSFET is fully charged. The PG pin is an active-high, open-drain output that requires an external pull up resistor,  $R_{PG}$ , greater than or equal to 1 k $\Omega$  to an external voltage source,  $V_{TERM}$ , compatible with input levels of other devices connected to this pin (as shown in Figures 30 and 31).

The power good output can be used as the enable signal for other active-high devices in the system (as shown in Figure 32). This allows for guaranteed by design power sequencing and reduces the number of enable signals needed from the system controller. If the power good feature is not used in the application, the PG pin should be tied to GND.

**Slew Rate Control**

The NCP45540 devices are equipped with controlled output slew rate which provides soft start functionality. This limits the inrush current caused by capacitor charging and enables these devices to be used in hot swap applications.

The slew rate can be decreased with an external capacitor added between the SR pin and ground (as shown in Figures 30 and 31). With an external capacitor present, the slew rate can be determined by the following equation:

$$\text{Slew Rate} = \frac{K_{SR}}{C_{SR}} \text{ [V/s]} \quad (\text{eq. 1})$$

where  $K_{SR}$  is the specified slew rate control constant, found in Table 4, and  $C_{SR}$  is the slew rate control capacitor added between the SR pin and ground. The slew rate of the device will always be the lower of the default slew rate and the adjusted slew rate. Therefore, if the  $C_{SR}$  is not large enough to decrease the slew rate more than the specified default value, the slew rate of the device will be the default value. The SR pin can be left floating if the slew rate does not need to be decreased.

**Short-Circuit Protection**

The NCP45540 devices are equipped with short-circuit protection that is used to help protect the part and the system from a sudden high-current event, such as the output,  $V_{OUT}$ , being shorted to ground. This circuitry is only active when the gate of the MOSFET is fully charged.

Once active, the circuitry monitors the difference in the voltage on the  $V_{IN}$  pin and the voltage on the BLEED pin. In order for the  $V_{OUT}$  voltage to be monitored through the BLEED pin, it is required that the BLEED pin be connected to  $V_{OUT}$  either directly (as shown in Figure 31) or through a resistor,  $R_{EXT}$  (as shown in Figure 30), which should not exceed 1 k $\Omega$ . With the BLEED pin connected to  $V_{OUT}$ , the short-circuit protection is able to monitor the voltage drop across the MOSFET.

If the voltage drop across the MOSFET is greater than or equal to the short-circuit protection threshold voltage, the MOSFET is immediately turned off and the load bleed is activated. The part remains latched in this off state until EN is toggled or  $V_{CC}$  supply voltage is cycled, at which point the MOSFET will be turned on in a controlled fashion with the normal output turn-on delay and slew rate. The current through the MOSFET that will cause a short-circuit event can be calculated by dividing the short-circuit protection threshold by the expected on-resistance of the MOSFET.

### Thermal Shutdown

The thermal shutdown of the NCP45540 devices protects the part from internally or externally generated excessive temperatures. This circuitry is disabled when EN is not active to reduce standby current. When an over-temperature condition is detected, the MOSFET is immediately turned off and the load bleed is activated.

The part comes out of thermal shutdown when the junction temperature decreases to a safe operating temperature as dictated by the thermal hysteresis. Upon exiting a thermal shutdown state, and if EN remains active, the MOSFET will be turned on in a controlled fashion with the normal output turn-on delay and slew rate.

### Undervoltage Lockout

The undervoltage lockout of the NCP45540 devices turns the MOSFET off and activates the load bleed when the input voltage,  $V_{IN}$ , is less than or equal to the undervoltage lockout threshold. This circuitry is disabled when EN is not active to reduce standby current.

If the  $V_{IN}$  voltage rises above the undervoltage lockout threshold, and EN remains active, the MOSFET will be turned on in a controlled fashion with the normal output turn-on delay and slew rate.

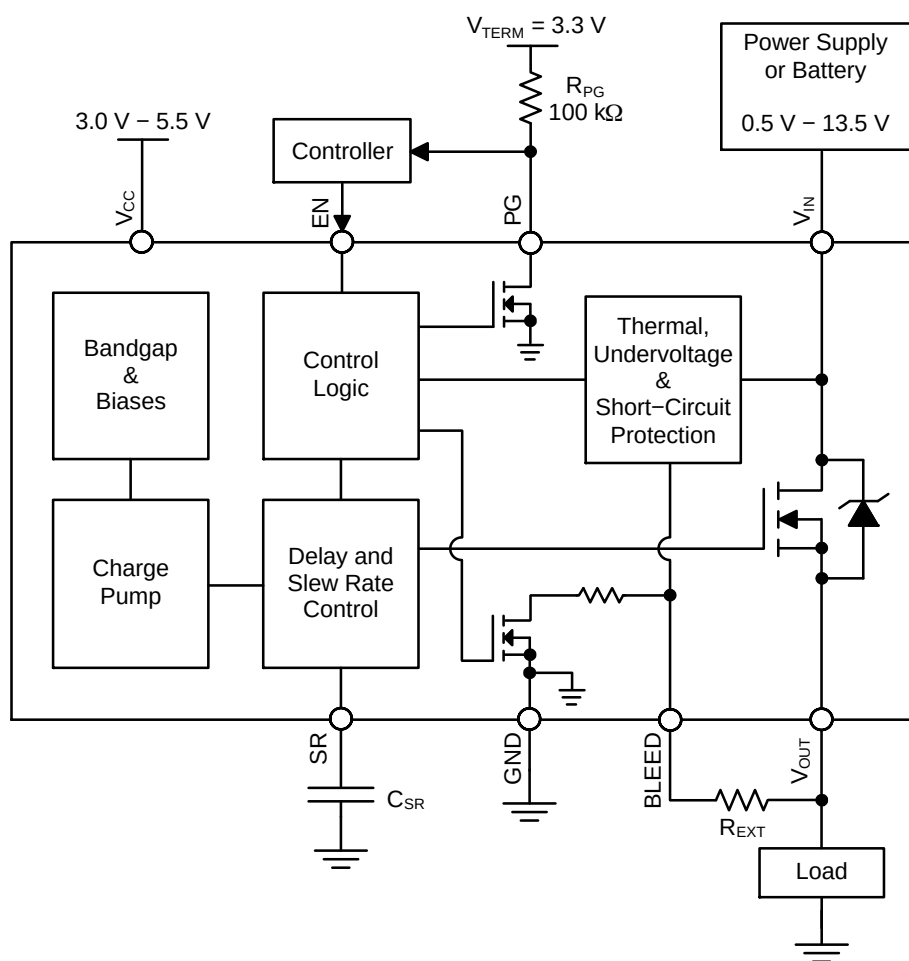


Figure 30. Typical Application Diagram – Load Switch

## NCP45540

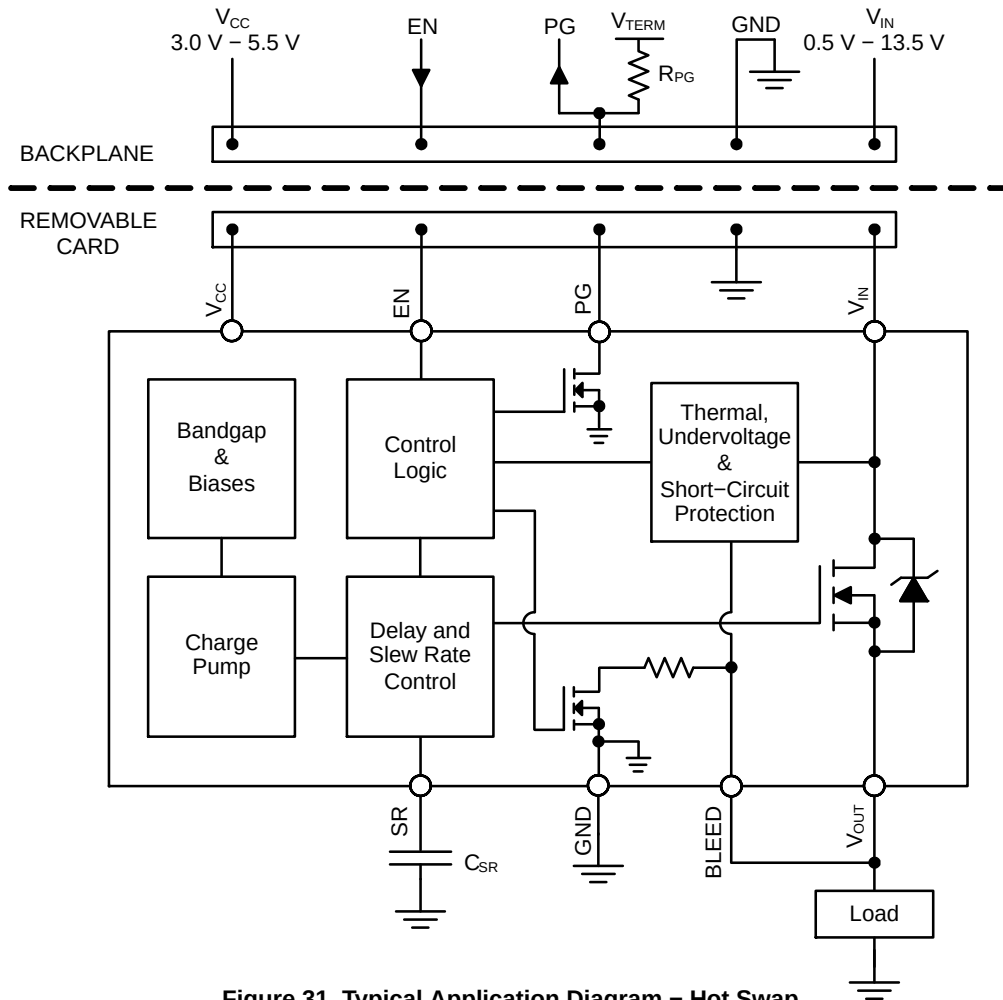


Figure 31. Typical Application Diagram – Hot Swap

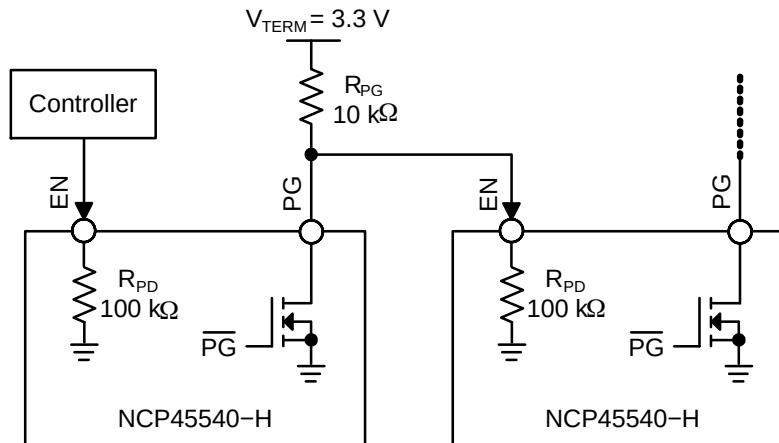


Figure 32. Simplified Application Diagram – Power Sequencing with PG Output

### ORDERING INFORMATION

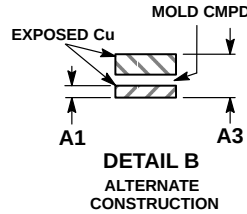
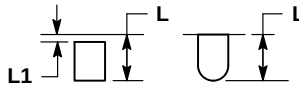
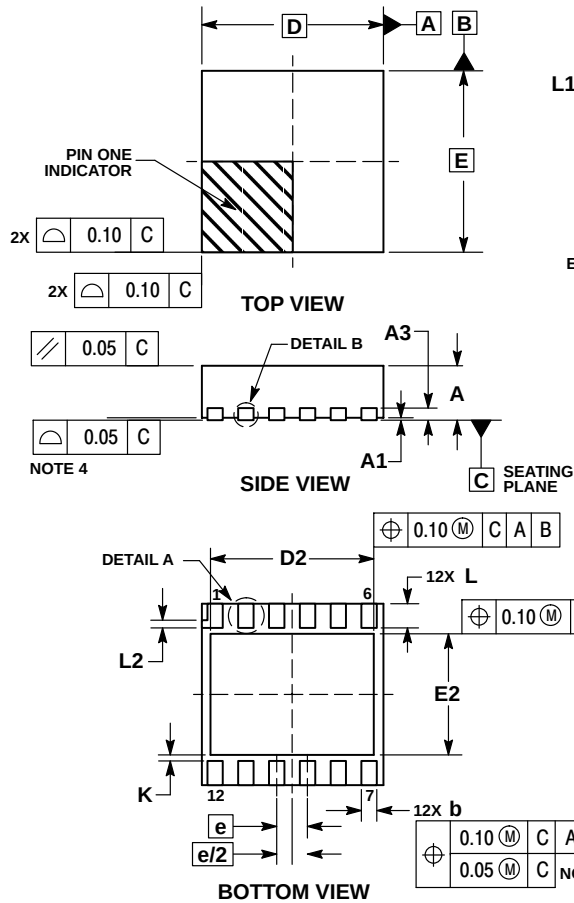
| Device           | EN Polarity | Package            | Shipping <sup>†</sup> |
|------------------|-------------|--------------------|-----------------------|
| NCP45540IMNTWG-H | Active-High | DFN12<br>(Pb-Free) | 3000 / Tape & Reel    |
| NCP45540IMNTWG-L | Active-Low  |                    |                       |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# NCP45540

## PACKAGE DIMENSIONS

DFN12 3x3, 0.5P  
CASE 506CD  
ISSUE A

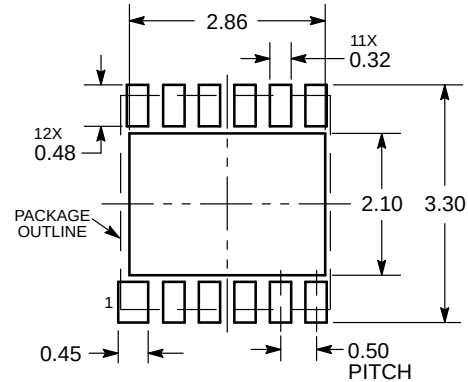


### NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 MM FROM TERMINAL TIP.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

| DIM | MIN  | MAX  |
|-----|------|------|
| A   | 0.80 | 1.00 |
| A1  | 0.00 | 0.05 |
| A3  | 0.20 | REF  |
| b   | 0.20 | 0.30 |
| D   | 3.00 | BSC  |
| D2  | 2.60 | 2.80 |
| E   | 3.00 | BSC  |
| E2  | 1.90 | 2.10 |
| e   | 0.50 | BSC  |
| L   | 0.20 | 0.40 |
| L1  | ---  | 0.15 |
| L2  | 0.10 | REF  |
| K   | 0.15 | MIN  |

### RECOMMENDED SOLDERING FOOTPRINT\*



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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